

# 3-to-8 Line Decoder MM74HCT138

# **General Description**

The MM74HCT138 decoder utilizes advanced silicon—gate CMOS technology, and are well suited to memory address decoding or data routing applications. Both circuits feature high noise immunity and low power consumption usually associated with CMOS circuitry, yet have speeds comparable to low power Schottky TTL logic.

The MM74HCT138 have 3 binary select inputs (A, B, and C). If the device is enabled these inputs determine which one of the eight normally HIGH outputs will go LOW. Two active LOW and one active HIGH enables (G1, G2A and G2B) are provided to ease the cascading decoders.

The decoders' output can drive 10 low power Schottky TTL equivalent loads and are functionally and pin equivalent to the 74LS138. All inputs are protected from damage due to static discharge by diodes to VCC and ground.

MM74HCT devices are intended to interface between TTL and NMOS components and standard CMOS devices. These parts are also plug—in replacements for LS-TTL devices and can be used to reduce power consumption in existing designs.

#### **Features**

- TTL Input Compatible
- Typical Propagation Delay: 20 ns
- Low Quiescent Current: 160 µA Maximum (74HCT Series)
- Low Input Current: 1 μA Maximum
- Fanout of 10 LS-TTL Loads
- These are Pb-Free Devices

#### **Connection Diagram**

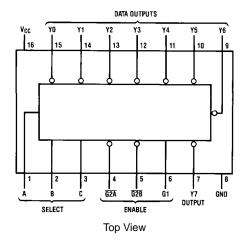


Figure 1. Pin Assignments for SOIC and TSSOP

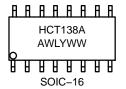


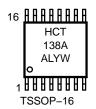
SOIC-16 CASE 751B-05/751BG-01



CASE 948F-01

#### MARKING DIAGRAM





HCT138A = Specific Device Code A = Assembly Location

WL, L = Wafer Lot Y = Year WW, W = Work Week

# **ORDERING INFORMATION**

See detailed ordering and shipping information on page 4 of this data sheet.

# **MM74HCT138**

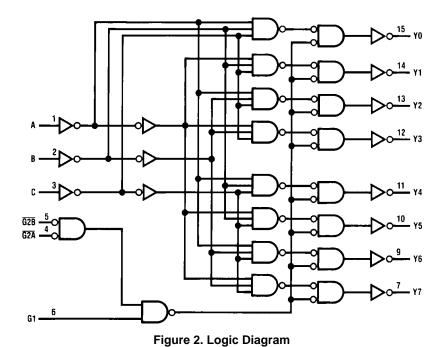
# **TRUTH TABLE**

		Inputs										
Er	Enable Select			Outputs								
G1	<b>G2</b> (Note 1)	С	В	Α	Y0	Y01	Y2	Y3	Y4	Y5	Y6	Y7
Х	Н	Х	Х	Х	Н	Н	Н	Н	Н	Н	Н	Н
L	Χ	Х	Х	Χ	Н	Н	Н	Н	Н	Н	Н	Н
Н	L	L	L	L	L	Н	Н	Н	Н	Н	Н	Н
Н	L	L	L	Н	Н	L	Н	Н	Н	Н	Н	Н
Н	L	L	Н	L	Н	Н	L	Н	Н	Н	Н	Н
Н	L	L	Н	Н	Н	Н	Н	L	Н	Н	Н	Н
Н	L	Н	L	L	Н	Н	Н	Н	L	Н	Н	Н
Н	L	Н	L	Н	Н	Н	Н	Н	Н	L	Н	Н
Н	L	Н	Н	L	Н	Н	Н	Н	Н	Н	L	Н
Н	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	L

H = HIGH Level L = LOW Level X = Don't Care

1.  $\overline{G2} = \overline{G2A} + \overline{G2B}$ 

# Logic Diagram



# **MM74HCT138**

# **ABSOLUTE MAXIMUM RATINGS** (Note 2)

Symbol		Parameter			
V <sub>CC</sub>	Supply Voltage		-0.5 to +7.0 V		
V <sub>IN</sub>	DC Input Voltage		–0.5 to V <sub>CC</sub> + 0.5 V		
V <sub>OUT</sub>	DC Output Voltage		–0.5 to V <sub>CC</sub> + 0.5 V		
I <sub>IK</sub> , I <sub>OK</sub>	Clamp Diode Current	±20 mA			
l <sub>OUT</sub>	DC Output Current, per Pin		±25 mA		
I <sub>CC</sub>	DC V <sub>CC</sub> or GND Current, per Pin		±50 mA		
T <sub>STG</sub>	Storage Temperature Range	Storage Temperature Range			
P <sub>D</sub>	Power Dissipation	500 mW			
TL	Lead Temperature (Soldering 10 S	260°C			

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

# RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V <sub>CC</sub>	Supply Voltage	4.5	5.5	V
V <sub>IN</sub> , V <sub>OUT</sub>	DC Input or Output Voltage	0	V <sub>CC</sub>	V
T <sub>A</sub>	Operating Temperature Range	<b>-</b> 55	+125	°C
t <sub>r</sub> , t <sub>f</sub>	Input Rise or Fall Times	-	500	ns

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

# **DC ELECTRICAL CHARACTERISTICS** ( $V_{CC} = 5 \text{ V} \pm 10\%$ (unless otherwise specified))

			T <sub>A</sub> =	25°C	$T_A = -40^{\circ}C$ to $85^{\circ}C$	T <sub>A</sub> = -55°C to 125°C	
Symbol	Parameter	Conditions	Тур		Guaranteed Limits		Unit
V <sub>IH</sub>	Minimum HIGH Level Input Voltage		-	2.0	2.0	2.0	V
V <sub>IL</sub>	Maximum LOW Level Input Voltage		-	0.8	0.8	0.8	V
V <sub>OH</sub>	Minimum HIGH Level Output Voltage	$\begin{split} &V_{IN} = V_{IH} \text{ or } V_{IL} \\ & I_{OUT}  = 20  \mu\text{A} \\ & I_{OUT}  = 4.0 \text{ mA, } V_{CC} = 4.5 \text{ V} \\ & I_{OUT}  = 4.8 \text{ mA, } V_{CC} = 5.5 \text{ V} \end{split}$	V <sub>CC</sub> 4.2 5.2	V <sub>CC</sub> - 0.1 3.98 4.98	V <sub>CC</sub> - 0.1 3.84 4.84	V <sub>CC</sub> - 0.1 3.7 4.7	V V V
V <sub>OL</sub>	Maximum LOW Level Voltage	$\begin{split} &V_{IN} = V_{IH} \text{ or } V_{IL} \\ & I_{OUT}  = 20  \mu\text{A} \\ & I_{OUT}  = 4.0 \text{ mA, } V_{CC} = 4.5 \text{ V} \\ & I_{OUT}  = 4.8 \text{ mA, } V_{CC} = 5.5 \text{ V} \end{split}$	0 0.2 0.2	0.1 0.26 0.26	0.1 0.33 0.33	0.1 0.4 0.4	V V V
I <sub>IN</sub>	Maximum Input Current	$V_{IN} = V_{CC}$ or GND, $V_{IH}$ or $V_{IL}$	-	±0.1	±1.0	±1.0	μΑ
I <sub>CC</sub>	Maximum Quiescent Supply Current	$V_{IN} = V_{CC}$ or GND, $I_{OUT} = 0 \mu A$	-	8.0	80	160	μΑ
		V <sub>IN</sub> = 2.4 V or 0.5 V (Note 3)	-	0.3	0.4	0.5	mA

<sup>3.</sup> This is measured per input pin. All other inputs are held at  $\ensuremath{V_{CC}}$  or ground.

<sup>2.</sup> Unless otherwise specified all voltages are referenced to ground.

# **MM74HCT138**

# AC ELECTRICAL CHARACTERISTICS ( $T_A = 25^{\circ}C$ , $V_{CC} = 5.0 \text{ V}$ , $t_r = t_f = 6 \text{ ns}$ , $C_L = 15 \text{ pF}$ (unless otherwise specified))

Symbol	Parameter	Conditions	Тур	Guaranteed Limit	Unit
t <sub>PHL</sub>	Maximum Propagation Delay, A, B, or C to Output		20	35	ns
t <sub>PLH</sub>	Maximum Propagation Delay, A, B, or C to Output		13	25	ns
t <sub>PHL</sub>	Maximum Propagation Delay, G1 to Y Output		14	25	ns
t <sub>PLH</sub>	Maximum Propagation Delay, G1 to Y Output		13	25	ns
t <sub>PHL</sub>	Maximum Propagation Delay, G2A or G2B to Y Output		17	30	ns
t <sub>PLH</sub>	Maximum Propagation Delay, G2A or G2B to Y Output		13	25	ns

# $\textbf{AC ELECTRICAL CHARACTERISTICS} \text{ ($V_{CC}$ = 5 V $\pm 10\%$, $C_L$ = 50 pF, $t_r$ = $t_f$ = 6 ns (unless otherwise specified))}$

			T <sub>A</sub> =	25°C	$T_A = -40^{\circ}C$ to $85^{\circ}C$	T <sub>A</sub> = -55°C to 125°C	
Symbol	Parameter	Conditions	Тур	Guaranteed Limits			Unit
t <sub>PHL</sub>	Maximum Propagation Delay A, B, or C to Output		24	40	50	60	ns
t <sub>PLH</sub>	Maximum Propagation Delay A, B, or C to Output		18	30	38	45	ns
t <sub>PHL</sub>	Maximum Propagation Delay G1 to Y Output		17	30	38	45	ns
t <sub>PLH</sub>	Maximum Propagation Delay G1 to Y Output		20	30	38	45	ns
t <sub>PHL</sub>	Maximum Propagation Delay G2A or G2B to Y Output		23	35	43	52	ns
t <sub>PLH</sub>	Maximum Propagation Delay G2A or G2B to Y Output		18	30	38	45	ns
$t_{THL}, t_{TLH}$	Maximum Output Rise and Fall Time		-	15	19	22	ns
C <sub>IN</sub>	Input Capacitance		_	5	10	10	pF
C <sub>PD</sub>	Power Dissipation Capacitance	(Note 4)	55	_	_	-	pF

<sup>4.</sup>  $C_{PD}$  determines the no load dynamic power consumption,  $P_D = C_{PD} \ V_{CC}^2 \ f + I_{CC} \ V_{CC}$ , and the no load dynamic current consumption,  $I_S = C_{PD} \ V_{CC} \ f + I_{CC}$ .

# **ORDERING INFORMATION**

Part Number	Package	Shipping <sup>†</sup>
MM74HCT138M	SOIC-16, Case 751B-05 (Pb-Free)	48 Units / Tube
MM74HCT138MTC	TSSOP-16, Case 948F-01 (Pb-Free)	96 Units / Tube
MM74HCT138MX	SOIC-16, Case 751BG-01 (Pb-Free)	2500 Units / Tape & Reel
MM74HCT138MTCX	TSSOP-16, Case 948F-01 (Pb-Free)	2500 Units / Tape & Reel

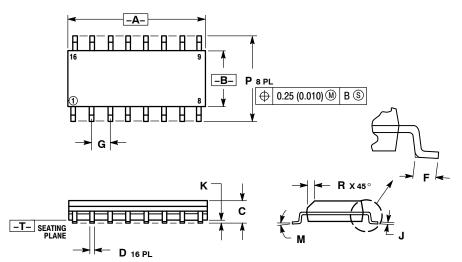
<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.





SOIC-16 CASE 751B-05 **ISSUE K** 

**DATE 29 DEC 2006** 



⊕ 0.25 (0.010) M T B S A S

- NOTES:

  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

  2. CONTROLLING DIMENSION: MILLIMETER.

  3. DIMENSIONS A AND B DO NOT INCLUDE MOLD ENGREPHING.

- PROTRUSION.

  MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
- DIMENSION D DOES NOT INCLUDE DAMBAR
  PROTRUSION. ALLOWABLE DAMBAR PROTRUSION. SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIN	IETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	9.80	10.00	0.386	0.393	
В	3.80	4.00	0.150	0.157	
C	1.35	1.75	0.054	0.068	
D	0.35	0.49	0.014	0.019	
F	0.40	1.25	0.016	0.049	
G	1.27	BSC	0.050 BSC		
J	0.19	0.25	0.008	0.009	
K	0.10	0.25	0.004	0.009	
M	0°	7°	0°	7°	
Р	5.80	6.20	0.229	0.244	
R	0.25	0.50	0.010	0.019	

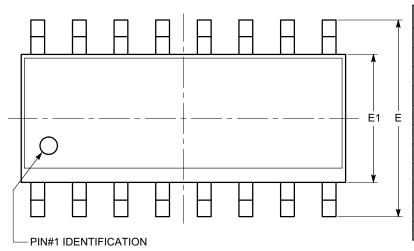
STYLE 1:		STYLE 2:		STYLE 3:		STYLE 4:		
	COLLECTOR		CATHODE		COLLECTOR, DYE #1		COLLECTOR, DYE #1	1
2.	BASE	2.	ANODE	2.	BASE, #1	2.	COLLECTOR, #1	
3.	EMITTER	3.	NO CONNECTION	3.	EMITTER, #1	3.	COLLECTOR, #2	
4.	NO CONNECTION	4.	CATHODE	4.	COLLECTOR, #1	4.	COLLECTOR, #2	
5.	EMITTER	5.	CATHODE	5.	COLLECTOR, #2	5.	COLLECTOR, #3	
6.	BASE	6.	NO CONNECTION	6.	BASE, #2	6.	COLLECTOR, #3	
7.	COLLECTOR	7.	ANODE	7.	EMITTER, #2	7.	COLLECTOR, #4	
8.	COLLECTOR	8.	CATHODE	8.	COLLECTOR, #2	8.	COLLECTOR, #4	
9.	BASE	9.	CATHODE	9.	COLLECTOR, #3	9.	BASE, #4	
10.	EMITTER	10.	ANODE	10.	BASE, #3	10.	EMITTER, #4	
11.	NO CONNECTION	11.	NO CONNECTION	11.	EMITTER, #3	11.	BASE, #3	
12.	EMITTER	12.	CATHODE	12.		12.	EMITTER, #3	DECOMMENDED
13.	BASE	13.	CATHODE	13.	COLLECTOR, #4	13.	BASE, #2	RECOMMENDED
14.	COLLECTOR	14.	NO CONNECTION	14.	BASE, #4	14.		SOLDERING FOOTPRINT*
15.	EMITTER	15.	ANODE	15.	EMITTER, #4	15.	BASE, #1	
16.	COLLECTOR	16.	CATHODE	16.	COLLECTOR, #4	16.	EMITTER, #1	8X
								<b>←</b> 6.40 <b>→</b>
STYLE 5:		STYLE 6:		STYLE 7:				
PIN 1.	DRAIN, DYE #1	PIN 1.	CATHODE	PIN 1.	SOURCE N-CH			16X 1.12 ← ➤
2.	DRAIN, #1	2.	CATHODE	2.	COMMON DRAIN (OUTPU	T)		
3.	DRAIN, #2	3.	CATHODE	3.	COMMON DRAIN (OUTPU	T)	1	1 16
4.	DRAIN, #2	4.	CATHODE	4.	GATE P-CH		<u>¥</u>	
5.	DRAIN, #3	5.	CATHODE	5.	COMMON DRAIN (OUTPU	T)	_	
6.	DRAIN, #3	6.	CATHODE	6.	COMMON DRAIN (OUTPU		16X	\ <u></u>
7.	DRAIN, #4	7.		7.	COMMON DRAIN (OUTPU	T)	0.58 -	
8.	DRAIN, #4	8.	CATHODE	8.	SOURCE P-CH			
9.	GATE, #4	9.	ANODE	9.	SOURCE P-CH	_		
10.	SOURCE, #4	10.	ANODE	10.	COMMON DRAIN (OUTPU		_	<del></del>
11.	GATE, #3	11.	ANODE	11.	COMMON DRAIN (OUTPU			
12.	SOURCE, #3	12.	ANODE	12.	COMMON DRAIN (OUTPU	1)		
13.	GATE, #2	13.	ANODE	13.	GATE N-CH	-		
14.	SOURCE, #2		ANODE	14.	COMMON DRAIN (OUTPU			\ PITCH
15.	GATE, #1	15.	ANODE	15.	COMMON DRAIN (OUTPU	1)		— — — — — — — — — — — — — — — — — — —
16.	SOURCE, #1	16.	ANODE	16.	SOURCE N-CH			
								□8 9 <del>-</del>
								DIMENSIONS: MILLIMETERS

\*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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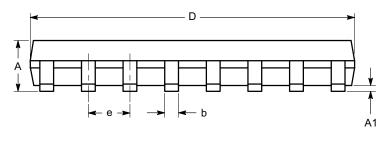
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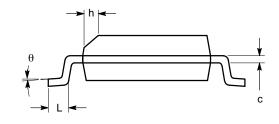
**DATE 19 DEC 2008** 



SYMBOL	MIN	NOM	MAX
Α	1.35		1.75
A1	0.10		0.25
b	0.33		0.51
С	0.19		0.25
D	9.80	9.90	10.00
E	5.80	6.00	6.20
E1	3.80	3.90	4.00
е		1.27 BSC	
h	0.25		0.50
L	0.40		1.27
θ	0°		8°

#### **TOP VIEW**





# **SIDE VIEW**

# **END VIEW**

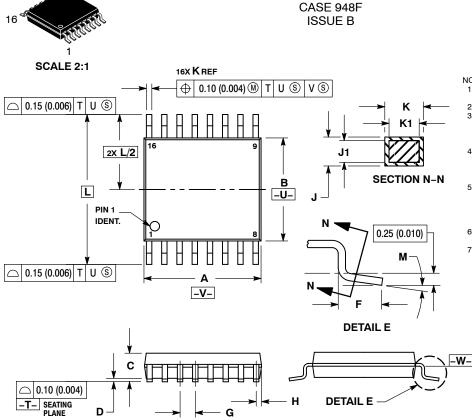
# Notes:

- (1) All dimensions are in millimeters. Angles in degrees.
- (2) Complies with JEDEC MS-012.

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TSSOP-16 WB

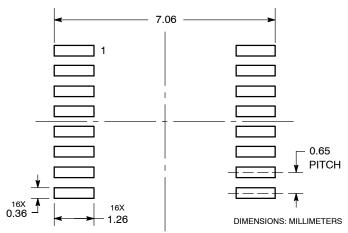
**DATE 19 OCT 2006** 

#### NOTES

- DIMENSIONING AND TOLERANCING PER
- ANSI Y14.5M, 1982. CONTROLLING DIMENSION: MILLIMETER.
- DIMENSION A DOES NOT INCLUDE MOLD FLASH. PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT
- EXCEED 0.15 (0.006) PER SIDE.
  DIMENSION B DOES NOT INCLUDE
  INTERLEAD FLASH OR PROTRUSION.
- INTERLEAD FLASH OR PROTRUSION.
  INTERLEAD FLASH OR PROTRUSION SHALL
  NOT EXCEED 0.25 (0.010) PER SIDE.
  DIMENSION K DOES NOT INCLUDE DAMBAR
  PROTRUSION. ALLOWABILE DAMBAR
  PROTRUSION SHALL BE 0.08 (0.003) TOTAL
  IN EXCESS OF THE K DIMENSION AT
  MAXIMUM MATERIAL CONDITION.
  TERMINIAL NILMBERS ADE SUCIUMI ECIP.
- TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
- DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α	4.90	5.10	0.193	0.200
В	4.30	4.50	0.169	0.177
С		1.20		0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
Н	0.18	0.28	0.007	0.011
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
Ы	6.40 BSC		0.252 BSC	
М	0 0	00	0 0	0 0

### **RECOMMENDED** SOLDERING FOOTPRINT\*



<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# **GENERIC** MARKING DIAGRAM\*



= Specific Device Code XXXX = Assembly Location Α

= Wafer Lot L = Year W = Work Week G or • = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present. Some products may not follow the Generic Marking.

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